TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

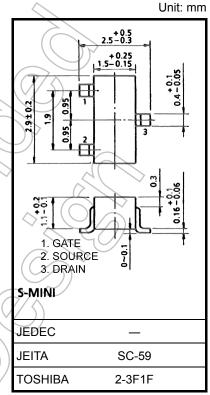
2SK1062

High Speed Switching Applications Analog Switching Applications Interface Applications

- Excellent switching time: ton = 14 ns (typ.)
- Low on resistance: RDS (ON) = 0.6Ω (typ.) @ ID = 50 mA
- Enhancement-mode
- Complementary to 2SJ168

Absolute Maximum Ratings (Ta = 25°C)

			1/		
Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	200	mA	
	Pulse	IDP	800		
Drain power dissipation (Ta = 25°C)		PD	200	mW	
Channel temperature		Tch	150	°C	
Storage temperature range		(T _{stg})	-55 to 150	°C	
				- 71	

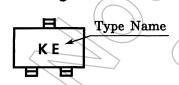


Weight: 0.012 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



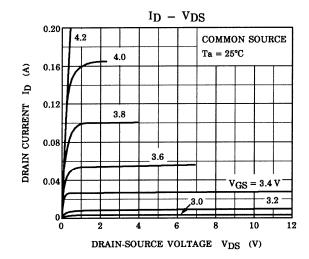
Electrical Characteristics (Ta = 25°C)

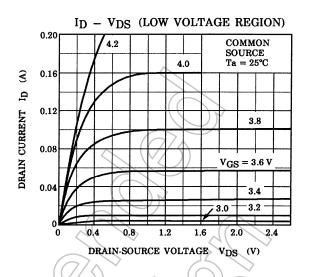
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA	
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0	_	_	10	μА	
Drain-source brea	kdown voltage	V (BR) DSS	I _D = 1 mA, V _{GS} = 0	60	_		V	
Gate threshold vo	Itage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2	_	3.5	V	
Forward transfer a	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 50 mA	100) /_		mS	
Drain-source ON I	resistance	R _{DS} (ON)	I _D = 50 mA, V _{GS} = 10 V) 	0.6	1.0	Ω	
Drain-source ON	voltage	V _{DS} (ON)	I _D = 50 mA, V _{GS} = 10 V	\mathcal{C}	30	50	mV	
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz)	55	65	pF	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	13	18	pF	
Output capacitance		C _{oss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	40	50	pF	
Switching time	Rise time	t _r	ID = 100 mA	TT (((((((((
	Turn-on time	t _{on}	VOUT	14) _	ns		
	Fall time	t _f	$V_{DD} = 30 \text{ V}$	(2)	35	_	115	
	Turn-off Time	t _{off}	V_{IN} : t_{r} , $t_{\text{f}} < 5$ ns D : $U \le 1\%$ $(Z_{\text{out}} = 50 \Omega)$) –	75			

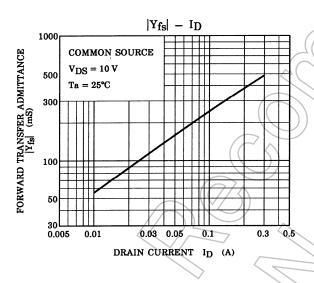
Note: This transistor is the electrostatic sensitive device. Please handle with caution.

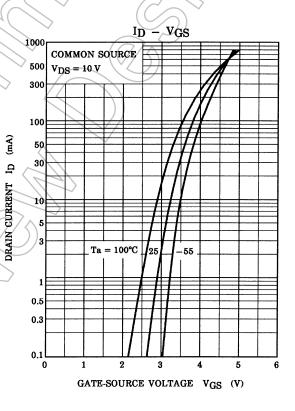


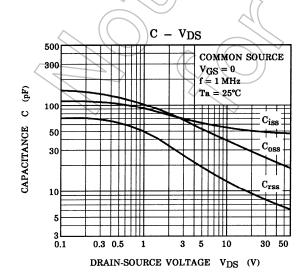
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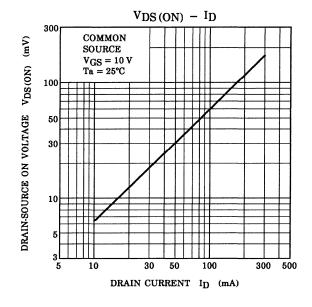


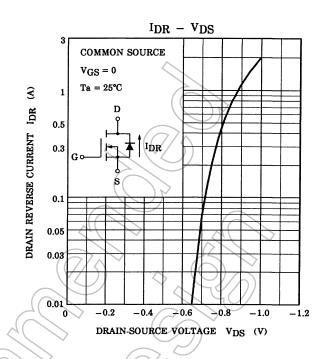


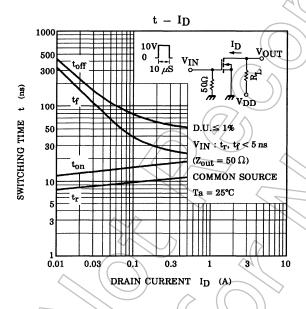


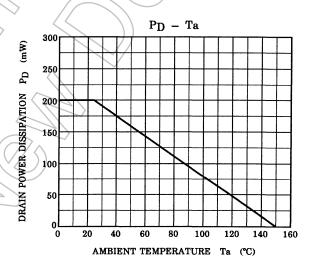


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